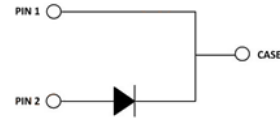




High Power SiC Schottky Barrier Diode ASA050V170B5



Package Type: TO-247-2L



Applications:

- Industrial power supplies:
Industrial UPS
- Battery chargers
- Solar inverters
- Switch mode power supplies

Features:

- Revolutionary semiconductor material - Silicon Carbide (SiC)
- No reverse recovery
- High-speed switching performance
- System cost / size saving due to reduced cooling requirement
- Junction Temp range -55°C to 175°C

Absolute Maximum Ratings (T_{amb}=25°C, unless specified otherwise)

Symbol	Parameter		ASA050V170B5	Unit
V _{DC}	DC reverse voltage		1700	V
V _{RRM}	Repetitive peak reverse voltage			
V _{RSM}	Surge peak reverse voltage			
I _F	Continuous Forward Current	T _C = 25°C	111	A
		T _C = 135°C	51	
		T _C = 136°C	50	
I _{FSM}	Surge non-repetitive forward current	T _C = 25°C, t _p = 10ms, half sine pulse	457	
I _{FRM}	Surge repetitive forward current	T _C = 25°C, t _p = 10ms, half sine wave D = 0.1	198	
P _{tot}	Total Power Dissipation		536	
j ² dt	i ² t value		1044	A ² s
T _j	Operating junction temperature range		-55 to 175	°C
T _{stg}	Storage temperature range		-55 to 175	
M	Mounting torque	M3 screw	1	Nm

Static Electrical Characteristics ($T_A = 25^\circ\text{C}$, unless specified otherwise)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{DC}	DC blocking voltage	$I_R = 100 \mu\text{A}$	1700	-	-	V
V_F	Forward voltage	$I_F = 50\text{A}, T_j = 25^\circ\text{C}$	-	1.40	1.60	V
		$I_F = 50\text{A}, T_j = 175^\circ\text{C}$	-	2.15	2.60	
I_R	Reverse current	$V_R = 1700\text{V}, T_j = 25^\circ\text{C}$	-	15	150	μA
		$V_R = 1700\text{V}, T_j = 175^\circ\text{C}$	-	75	1000	

Thermal Characteristics

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
$R_{\theta JC}$	Junction-to-case Thermal Resistance		-	0.28	-	$^\circ\text{C}/\text{W}$

Dynamic Characteristics ($T_A = 25^\circ\text{C}$, unless specified otherwise)

C	Total capacitance	$V_R = 0\text{V}, f = 1\text{MHz}$	-	4065	-	pF
		$V_R = 600\text{V}, f = 1\text{MHz}$	-	221	-	
		$V_R = 1200\text{V}, f = 1\text{MHz}$	-	160	-	
Q_C	Total capacitive charge	$V_R = 1200\text{V}$	-	360	-	nC
E_C	Capacitance stored energy	$V_R = 1200\text{V}$	-	151	-	μJ

Electrical Characteristic Diagrams

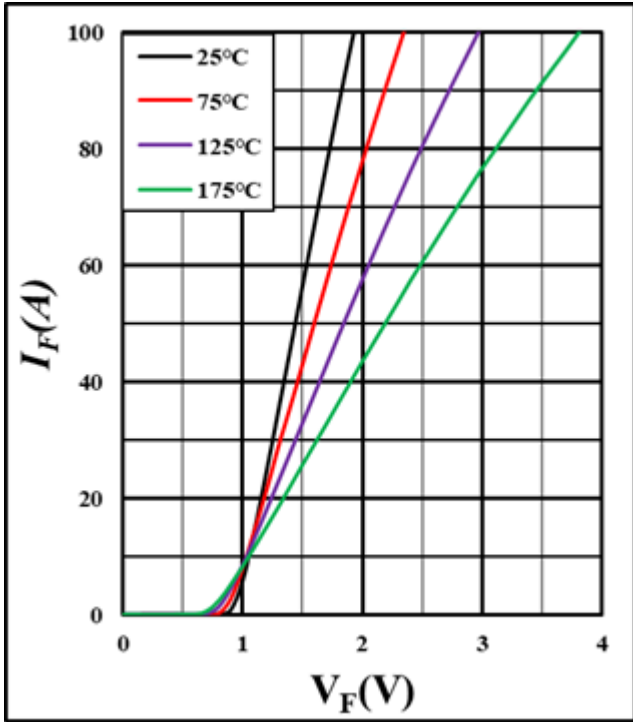


Figure 1. Forward characteristics

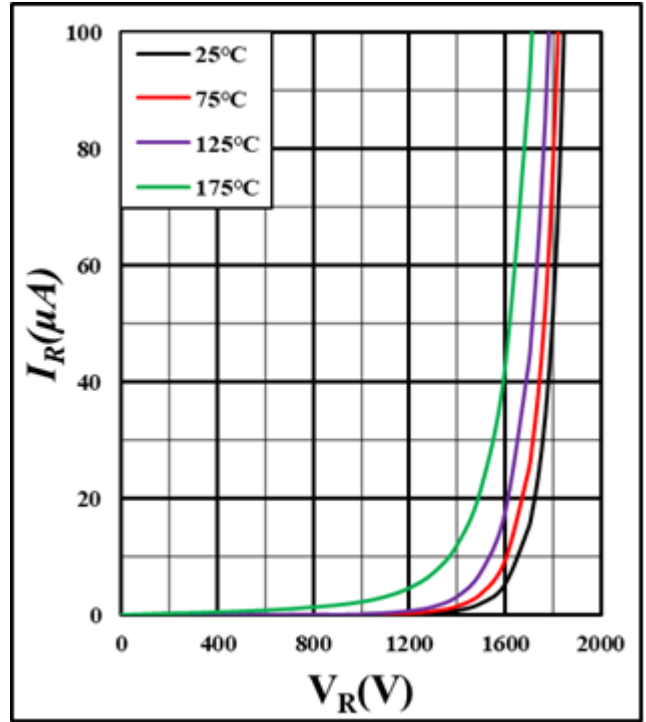


Figure 2. Reverse characteristics

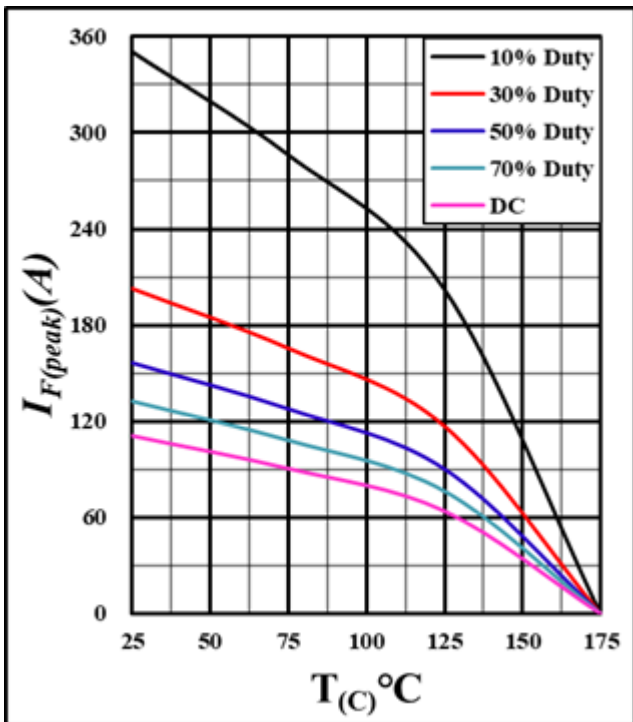


Figure 3. Current derating

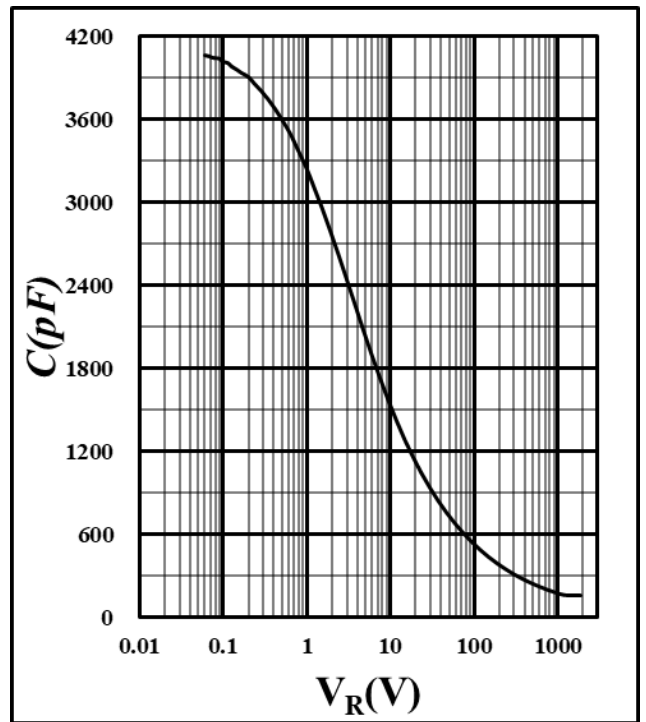


Figure 4. Capacitance vs. reverse voltage

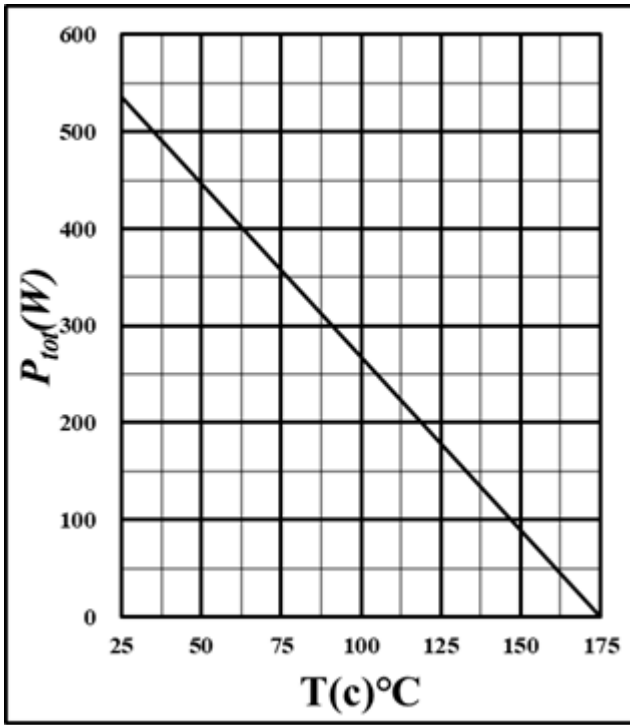


Figure 5. Power derating

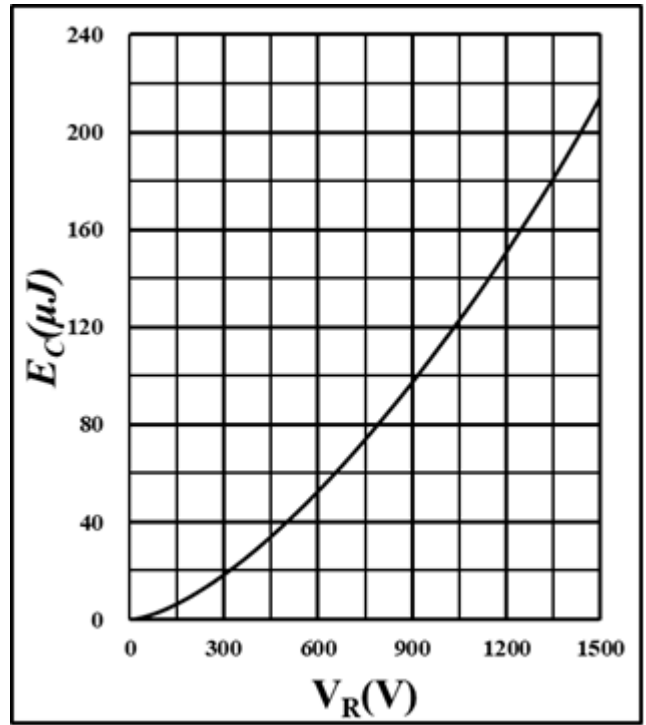


Figure 6. Capacitance stored energy

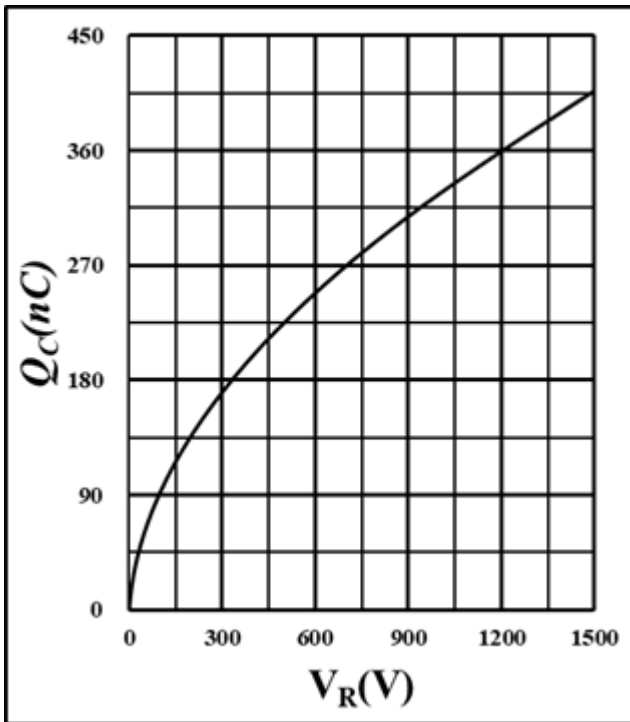
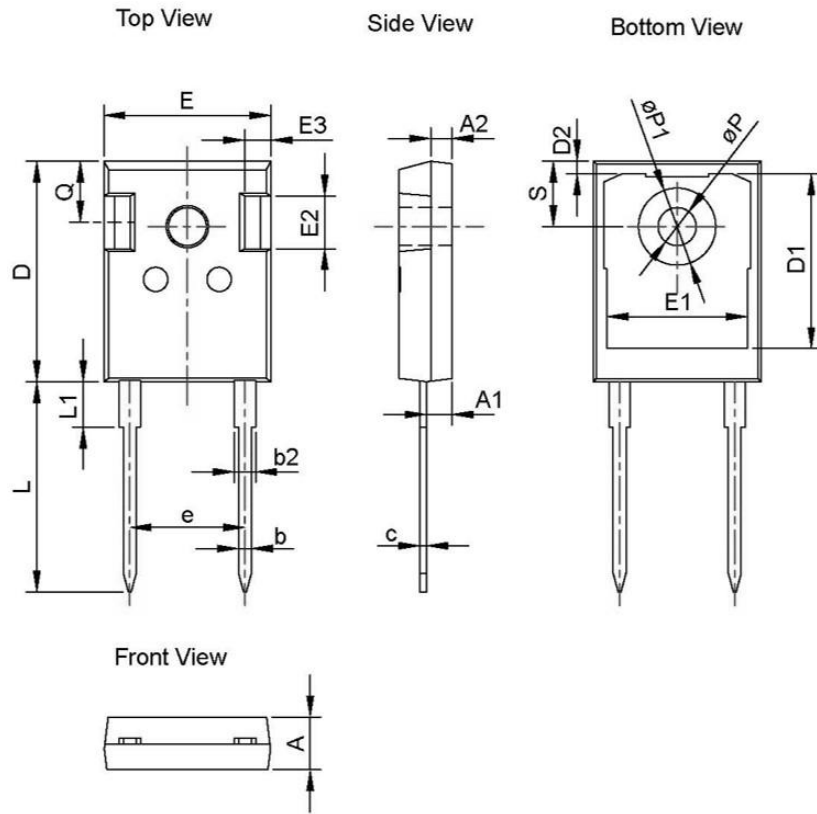


Figure 7. Total capacitance charge vs. reverse voltage

Package Information



Dimension unit: [mm]			
Symbol	Min	Nom	Max
A	4.80	5.00	5.20
A1	2.21	2.41	2.61
A2	1.85	2.00	2.15
b	1.11	1.21	1.36
b2	1.91	2.01	2.21
c	0.51	0.60	0.75
D	20.70	21.00	21.30
D1	16.25	16.55	16.85
D2	1.00	1.20	1.35
E	15.50	15.80	16.10
E1	13.00	13.30	13.60
E2	4.80	5.00	5.20
E3	2.30	2.50	2.70
e	10.88 BSC		
L	19.62	19.92	20.22
L1	-	-	4.30
ϕP	3.40	3.60	3.80
$\phi P1$	-	-	7.30
Q	5.40	5.80	6.20
S	6.20 BSC		

Recommended Solder Pad Layout

Note: All dimensions are in mm



TO-247-2L

Ordering Information

Part number	ASA050V170B5
Package	TO-247-2L
Unit quantity	300 EA
Packing type	Tube